

HRC0201A

Silicon Schottky Barrier Diode for Rectifying

REJ03G0618-0100

(Previous: ADE-208-1559)

Rev.1.00

May 17, 2005

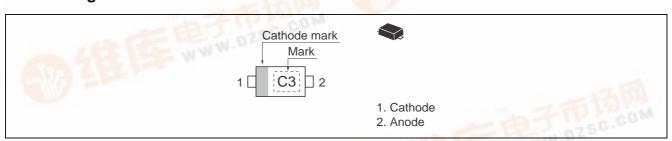
Features

- Low forward voltage drop and suitable for high efficiency rectifying.
- Ultra small Flat Lead Package (UFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Name	Package Code (Previous Code)
HRC0201A	C3	UFP	PWSF0002ZA-A (UFP)

Pin Arrangement





Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Repetitive peak reverse voltage	V _{RRM} * ¹	15	V
Reverse voltage	V _R	15	V
Average rectified current	I _O * ¹ 200		mA
Peak forward current	I _{FM}	300	mA
Non-Repetitive peak forward surge current	I _{FSM} * ²	1	А
Junction temperature	Tj	125	°C
Storage temperature	Tstg	−55 to +125	°C

Notes: 1. See from Fig.4 to Fig.6, with polyimide board.

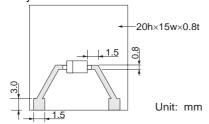
2. 10 ms sine wave 1 pulse.

Electrical Characteristics

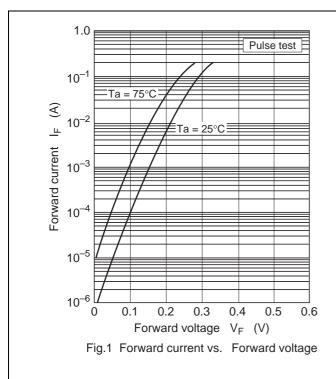
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V _F	_	_	0.39	V	I _F = 200 mA
Reverse current	I _R	_	_	50	μΑ	V _R = 6 V
Capacitance	С	_	18	_	pF	V _R = 1 V, f = 1 MHz
Thermal resistance	Rth(j-a)	_	600	_	°C/W	Polyimide board *1

Note: 1. Polyimide board



Main Characteristic



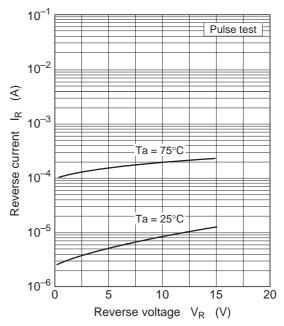
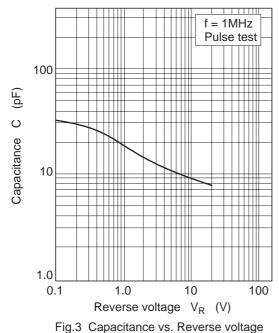
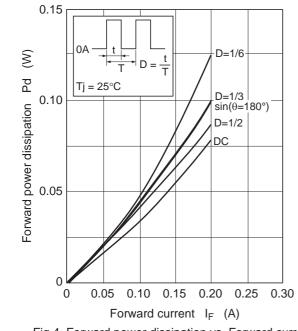


Fig.2 Reverse current vs. Reverse voltage







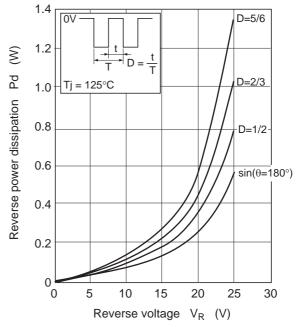


Fig.5 Reverse power dissipation vs. Reverse voltage

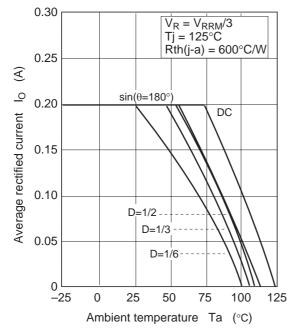
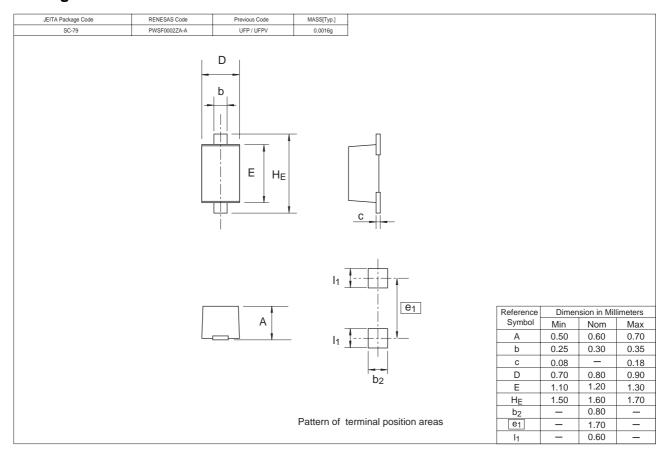


Fig.6 Average rectified current vs. Ambient temperature

Package Dimensions



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